

Fast Recovery Epitaxial Diode (FRED) Module

PSND 200E

$$\begin{aligned} I_{FAV} &= 312 \text{ A} \\ V_{RRM} &= 800-1200 \text{ V} \end{aligned}$$

Preliminary Data Sheet

V_{RSM}	V_{RRM}	Type
V	V	
800	800	PSND 200E/08
1000	1000	PSND 200E/10
1200	1200	PSND 200E/12



Symbol	Test Conditions			Maximum Ratings	
I_{FAV}	$T_C = 70^\circ\text{C}$			312	A
I_{FSM}	$T_{VJ} = 45^\circ\text{C}$	$t = 10 \text{ ms}$	(50 Hz), sine	3200	A
	$V_R = 0$	$t = 8.3 \text{ ms}$	(60 Hz), sine	3500	A
	$T_{VJ} = T_{VJM}$	$t = 10 \text{ ms}$	(50 Hz), sine	2900	A
	$V_R = 0$	$t = 8.3 \text{ ms}$	(60 Hz), sine	3200	A
$\int i^2 dt$	$T_{VJ} = 45^\circ\text{C}$	$t = 10 \text{ ms}$	(50 Hz), sine	51200	$\text{A}^2 \text{ s}$
	$V_R = 0$	$t = 8.3 \text{ ms}$	(60 Hz), sine	50800	$\text{A}^2 \text{ s}$
	$T_{VJ} = T_{VJM}$	$t = 10 \text{ ms}$	(50 Hz), sine	42000	$\text{A}^2 \text{ s}$
	$V_R = 0$	$t = 8.3 \text{ ms}$	(60 Hz), sine	42500	$\text{A}^2 \text{ s}$
T_{VJ}				-40 ... + 150	$^\circ\text{C}$
T_{VJM}				150	$^\circ\text{C}$
T_{stg}				-40 ... + 125	$^\circ\text{C}$
V_{ISOL}	50/60 HZ, RMS	$t = 1 \text{ min}$		2500	V ~
	$I_{ISOL} \leq 1 \text{ mA}$	$t = 1 \text{ s}$		3000	V ~
M_d	Mounting torque		(M6)	5	Nm
	Terminal connection torque		(M6)	5	Nm
Weight	typ.			270	g

Symbol	Test Conditions		Characteristic Value		
I_R	$V_R = V_{RRM}$	$T_{VJ} = 25^\circ C$	\leq	3.4	mA
	$V_R = V_{RRM}$	$T_{VJ} = T_{VJM}$	\leq	35	mA
V_F	$I_F = 200 \text{ A}$	$T_{VJ} = 25^\circ C$	\leq	1.55	V
t_{rr}	$T_{VJ} = 25^\circ C$		typ.	150	ns
V_{TO}	For power-loss calculations only			0.3	V
r_T	$T_{VJ} = T_{VJM}$			0.75	$m\Omega$
R_{thJC}	per diode; DC current			0.28	K/W
	per module			0.14	
R_{thJH}	per diode; DC current			0.38	K/W
	per module			0.19	
d_s	Creeping distance on surface			10	mm
d_A	Creeping distance in air			9.4	mm
a	Max. allowable acceleration			50	m/s^2

Features

- Package with screw terminals
 - Isolation voltage 3000 V~
 - Planar glasspassivated chips
 - Short recovery time
 - Low forward voltage drop
 - Short recovery behaviour
 - UL registered, E 148688

Applications

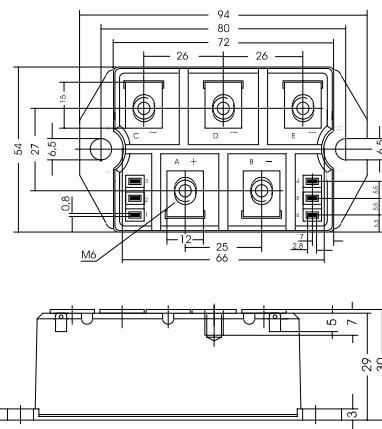
- Inductive heating and melting
 - Free wheeling diode in converters and motor control circuits
 - Uninterruptible power supplies (UPS)
 - Ultrasonic cleaners and welders

Advantages

- High reliability circuit operation
 - Low voltage peaks for reduced protection circuits
 - Low noise switching
 - Low losses

Package, style and outline

Dimensions in mm (1mm = 0.0394")



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